

HMC939LP4 / 939LP4E

v01.1211



1.0 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 33 GHz

Typical Applications

The HMC939LP4 / HMC939LP4E is ideal for:

- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar & ECM
- Space Applications
- Sensors
- Test & Measurement Equipment

Features

1.0 dB LSB Steps to 31 dB

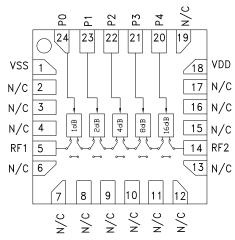
Single Positive Control Line Per Bit

±1.0 dB Typical Bit Error

High Input IP3: +43 dBm

16mm² Leadless SMT Plastic Package

Functional Diagram



General Description

The HMC939LP4 & HMC939LP4E are broadband 5-bit GaAs IC digital attenuators in low cost leadless surface mount packages. Covering 0.1 to 33.0 GHz, the insertion loss is less than 5 dB typical. The attenuator bit values are 1.0 (LSB), 2, 4, 8, 16 for a total attenuation of 31 dB. Attenuation accuracy is excellent at ± 0.4 dB typical step error with an IIP3 of ± 4.3 dBm. Five control voltage inputs, toggled between ± 5.0 and 0V, are used to select each attenuation state.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, With Vdd = +5V, Vss = -5V, P0 - P4 = 0/ +5V

Parameter	Freque	ency (GHz)	Min.	Тур.	Max.	Units
Insertion Loss	18.0 -	18.0 GHz 26.5 GHz 33.0 GHz		4.0 5.5 6.5	5.5 7.0 8.5	dB dB dB
Attenuation Range	0.1 -	33.0 GHz		31		dB
Return Loss (RF1 & RF2, All Atten. States)	0.1 -	33.0 GHz		12		dB
Attenuation Accuracy: (Referenced to Insertion Loss) 1.0 - 15 dB States 16 - 31 dB States 16 - 31 dB States		33.0 GHz 20.0 GHz 33.0 GHz	± (0.5 + 5%) of Atten. Setting Max ± (0.5 + 5%) of Atten. Setting Max ± (0.6 + 8%) of Atten. Setting Max		dB dB dB	
Input Power for 0.1 dB Compression	_	0.5 GHz 33.0 GHz		20 25		dBm dBm
Input Third Order Intercept Point (Two-Tone Input Power= 0 dBm Each Tone)		0.5 GHz 33.0 GHz		40 43		dBm dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON/tOFF (50% CTL to 10/90% RF)		33.0 GHz		60 90		ns ns
ldd	0.1 -	33.0 GHz	2.5	4.5	6.5	mA
Iss	0.1 -	33.0 GHz	-7.0	-5.0	-3.0	mA

HMC939* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS 🖳

View a parametric search of comparable parts.

EVALUATION KITS

· HMC939LP4E Evaluation Board

DOCUMENTATION

Data Sheet

- · HMC939 Die Data Sheet
- HMC939LP4 Data Sheet

TOOLS AND SIMULATIONS 🖵

- HMC939 Die S-Parameters
- HMC939LP4 S-Parameters

REFERENCE MATERIALS 🖵

Quality Documentation

Semiconductor Qualification Test Report: PHEMT-D (QTR: 2013-00254)

DESIGN RESOURCES

- HMC939 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC939 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK 🖳

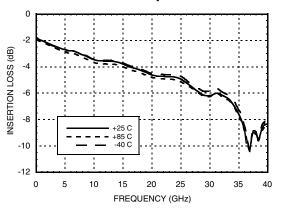
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Insertion Loss vs. Temperature

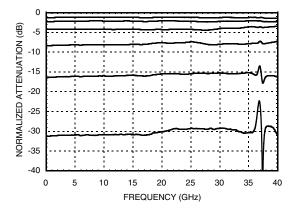


ATTENUATOR, 0.1 - 33 GHz

1.0 dB LSB GaAs MMIC 5-BIT DIGITAL

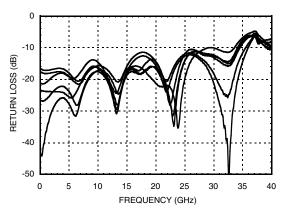
Normalized Attenuation

(Only Major States are Shown)



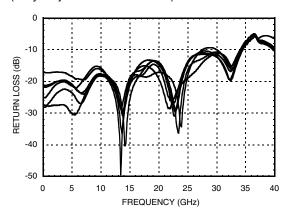
Input Return Loss

(Only Major States are Shown)

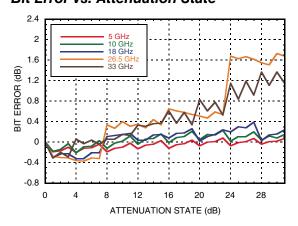


Output Return Loss

(Only Major States are Shown)

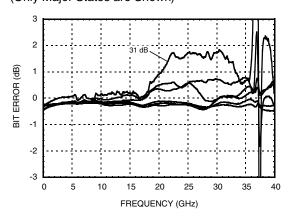


Bit Error vs. Attenuation State



Bit Error vs. Frequency

(Only Major States are Shown)

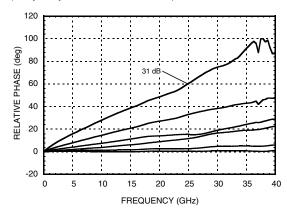




ROHS V

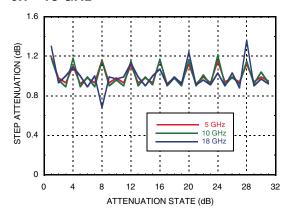
Relative Phase vs. Frequency

(Only Major States are Shown)

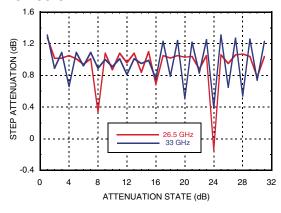


1.0 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 33 GHz

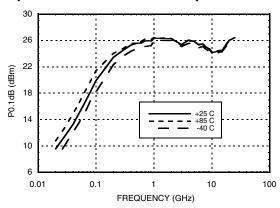
Step Attenuation vs. Attenuation State 0.1 - 18 GHz



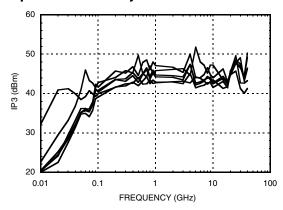
Step Attenuation vs. Attenuation State 18 - 33 GHz



Input Power for 0.1 dB Compression

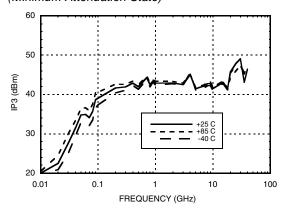


Input IP3 Over Major Attenuation States



Input IP3 vs. Temperature

(Minimum Attenuation State)







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Absolute Maximum Ratings

RF Input Power (0.1 to 33.0 GHz)	+25 dBm
Control Voltage (P0 to P4)	Vdd + 0.5V
Vdd	+7 Vdc
Vss	-7 Vdc
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 6.8 mW/°C above 85 °C)	0.451 W
Thermal Resistance	144 °C/W
Storage Temperature	-65 to + 150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Bias Voltages & Currents

Vdd	+5V @ 4.5 mA	
Vss	-5V @ 5 mA	

Control Voltage

State	Bias Condition
Low	0 to 0.8V @ 1 μA
High	2 to 5V @ 1 μA



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing

.039 1.00 0.80 .002 [0.05] .000 [0.00] .000 SEATING PLANE .003[0.08] C

NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
 PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC939LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H939 XXXX
HMC939LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>H939</u> XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX





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Truth Table

Control Voltage Input					Attenuation	
P4 16 dB	P3 8 dB	P2 4 dB	P1 2 dB	P0 1 dB	State RF1 - RF2	
High	High	High	High	High	Reference I.L.	
High	High	High	High	Low	1 dB	
High	High	High	Low	High	2 dB	
High	High	Low	High	High	4 dB	
High	Low	High	High	High	8 dB	
Low	High	High	High	High	16 dB	
Low	Low	Low	Low	Low	31 dB	

Any Combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

Pin Descriptions

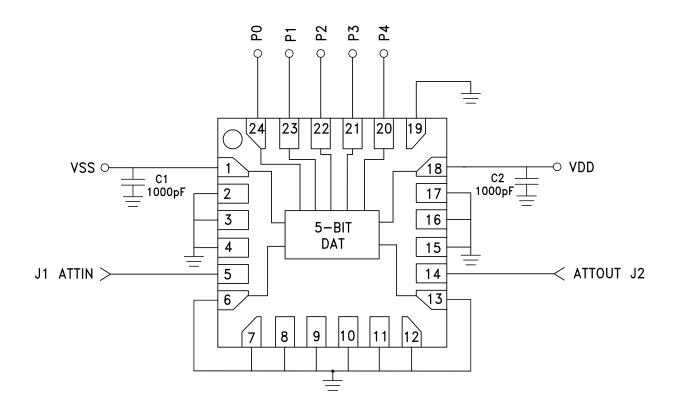
Pad Number	Function	Description	Interface Schematic
1	Vss	Negative Bias -5V	Vss 3pF =
2-4, 6-13, 15-17, 19	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
5, 14	RF1, RF2	These pins are DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.	
18	Vdd	Positive Bias +5V	Vdd 3pF =
20 - 24	P0 - P4	See truth table and control voltage table.	P0-P4 0
	GND	Package bottom must be connected to RF/DC ground.	○ GND =





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Application Circuit

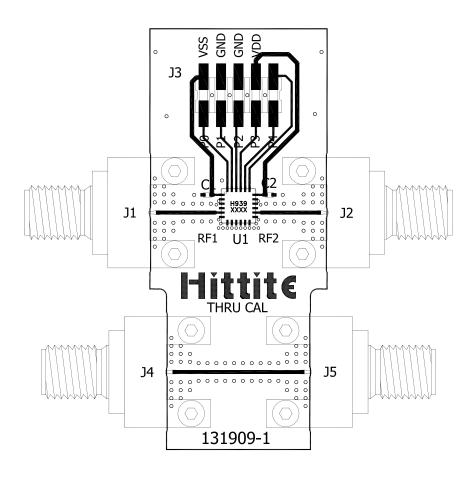






Evaluation PCB

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List of Materials for Evaluation PCB 130450 [1]

Item	Description
J1, J2, J4, J5	2.9 mm PC Mount RF Connector
J3	DC Connector
C1, C2	1000 pF Capacitor, 0402 Pkg.
U1	HMC939LP4 Digital Attenuator
PCB [2]	131909 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



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